## DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION

DOCKET NO. **TS02-066** 

As a below named Inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name;

No.6, Li-Hsin Rd. 6, Science-Based Industrial Park, Hsin-Chu, Taiwan 300-77 R.O.C. Post Office Address

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled **Method Of Forming Dual Gate Insulator Layers For Cmos Applications** 

the specification of which (check one)			
X is attached hereto.			
was filed on			
Application Serial No.			
and was amended on(i	familiashla		
I hereby state that I have reviewed and amended by any amendment referred t		pove Identified specification including the cla	aims, as
I acknowledge the duty to disclose info Title 37, Code of Federal Regulations,	ormation which is material to the §1.56(a).	examination of this application in accordance	e with
I hereby claim foreign priority benefits inventor's certificate listed below and having a filing date before that of the a Prior Foreign Application(s)	have also identified below any for	de §119 of any foreign application(s) for pat reign application for patent or inventor's cert aimed:	ent or ificate
· · · · · · · · · · · · · · · · · · ·		Priority Claimed:	
(Number)	(Country)	(Day/Month/Year Filed)	
(Number)	(Country)	(Day/Month/Year Filed)	
I hereby claim the benefit under Title 3 as the subject matter of each of the cla manner provided by the first paragraph information as defined in Title 37, Coapplication and the national or PCT in	35, United States Code §120 of ar ims of this application is not disci n of Title 35, United States Code, de of Federal Regulations, §1.56(a ternational filing date of this appl	ny United States application(s) listed below a losed in the prior United States application ir §112, I acknowledge the duty to disclose ma a) which occurred between the filing date of ication:	ind, insofar i the iterial the prior
(Application Serial No.)	(Filing Date) (Status)	(patented, pending, abandoned)	
I hereby declare that all statements ma belief are believed to be true; and furth the like so made are punishable by fine and that such willful false statements r	de herein of my own knowledge a ner that these statements were made or imprisonment, or both, under nay jeopardize the validity of the	tre true and that all statements made on informulation in the with the knowledge that willful false states. Section 1001 of Title 18 of the United State application or any patent issued thereon.	mation and ments and s Code
POWER OF ATTORNEY: As a name application and transact all business in	ed inventor, I hereby appoint the father than the Patent and Trademark Office	ollowing attorney(s) and/or agent(s) to prose connected therewith. (list name & registration	cute this on no.)
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Citizenship	
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Full name of sixth inventor	Date
Inventor's signature	
Residence	
Citizenship	<del></del>
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